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Substitute for form 1449A/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Sheet	1	of	1	Attorney Docket Number	740756-2296
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Complete if Known

Application Number	09/837,552
Filing Date	April 19, 2001
First Named Inventor	Hisashi OHTANI et al.
Art Unit	2815
Examiner Name	Andrew Richards

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	U.S. Patent Document		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number - Kind Code ² (if known)	Kind Code ³ (if known)			
ASR		US-2001/0030722 A1		10/18/2001	Murade	
ASR		US-2002/0080295 A1		06/27/2002	Someya et al.	
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FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Foreign Patent Document		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T*
		Country Code ⁴ Number ⁵	Kind Code ⁶ (if known)				

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T*
ASR		Byeon, Sang Gi et al. "High-Performance Tantalum Oxide Capacitors Fabricated by a Novel Reoxidation Scheme" IEEE Transactions On Electron Devices, Vol. 37, No. 4, April 1990	

Examiner Signature	<i>mjl/2004</i>	Date Considered	1/26/04
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